

## Maximum Ratings

Symbol	Conditions	Values	Units
$V_{CEVsus}$	$I_C = 1 \text{ A}, V_{BE} = -2 \text{ V}$	600	V
$V_{CEV}$	$V_{BE} = -2 \text{ V}$	600	V
$V_{CBO}$	$I_E = 0$	600	V
$V_{EBO}$	$I_C = 0$	7	V
$I_C$	D. C.	300	A
$I_F = -I_C$	D. C.	300	A
$I_B$		18	A
$P_{tot}$	$T_{case} = 25 \text{ }^\circ\text{C}$	1380	W
$T_{vj}$		-40 ... +150	$^\circ\text{C}$
$T_{stg}$		-40 ... +125	$^\circ\text{C}$
$V_{isol}$	a. c. 50 Hz, r.m.s.	2500~	V

## Thermal Characteristics

$R_{thjc}$	darlington	0,09	$^\circ\text{C/W}$
$R_{thjc}$	diode	0,3	$^\circ\text{C/W}$
$R_{thch}$	module	0,04	$^\circ\text{C/W}$

Electrical Characteristics<sup>1)</sup>

		min.	typ.	max.	
$I_{CEV}$	$V_{CE} = V_{CEV}, V_{BE} = -2 \text{ V}$			4	mA
$I_{EBO}$	$I_C = 0, V_{BE} = -7 \text{ V}$			800	mA
$V_{CEsat}^{2)}$	$I_C = 300 \text{ A}, I_B = 4 \text{ A}$			2	V
$V_{BEsat}^{2)}$	$I_C = 300 \text{ A}, I_B = 4 \text{ A}$			2,5	V
$h_{21E}^{2)}$	$I_C = 300 \text{ A}$	$V_{CE} = 2 \text{ V}$	75		
		$V_{CE} = 5 \text{ V}$	100		

Switching Characteristics for Resistive Load<sup>1)</sup>

$t_{on}$	} $I_C = 300 \text{ A}$ $I_{B1} = -I_{B2} = 6 \text{ A}$ $V_{CC} = 300 \text{ V}$			2,5	$\mu\text{s}$
$t_s$				12	$\mu\text{s}$
$t_f$				3	$\mu\text{s}$

Inverse Diode Characteristics<sup>1)</sup>

$V_F = -V_{CE}$	$I_F = -I_C = 300 \text{ A}$			1,85	V
$I_{FSM} = -I_{Cp}$	$\sin 180^\circ, 10 \text{ ms}$	3000			A
$I_{RM}$	} $I_F = -I_C = 300 \text{ A}, -di_F/dt = 100 \text{ A}/\mu\text{s}$ $V_{BE} = -3 \text{ V}, V_R = V_{CE} = 400 \text{ V},$ $T_{vj} = 125 \text{ }^\circ\text{C}$			50	A
$Q_{rr}$				25	$\mu\text{C}$

## Mechanical Data

$M_1$	Case to heatsink	SI units	3		6	Nm	
		US units	27		53	lb. in.	
$M_2$	Busbars to	terminals 1, 2	SI units	2,5		5	Nm
			US units	22		44	lb. in.
		terminals 3 ... 5	SI units	1,1		2	Nm
			US units	10		18	lb. in.
$w$			475		g		
Case			D 19				

<sup>1)</sup>  $T_{case} = 25 \text{ }^\circ\text{C}$  unless otherwise stated

<sup>2)</sup>  $t_p \leq 300 \mu\text{s}, D \leq 1,5\%$

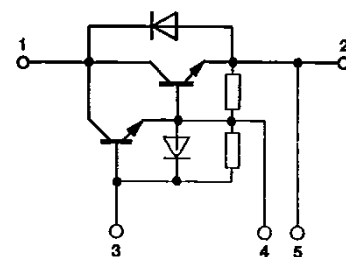
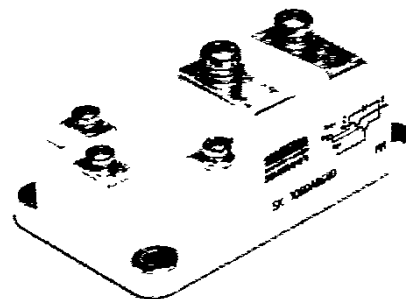
# SEMITRANS® 4 NPN

## Power Darlington Modules

### 300 A, 600 V

SK 300 DA 060 D

T-33-35



## Features

- Isolated baseplate (ease of mounting of one or several modules on one heatsink)
- All electrical connections on top (ease of interconnecting of modules with busbars)
- Large clearances and creepage distances
- Parallel connected fast recovery inverse diode
- UL recognized, file no. E 63 532

## Typical Applications

- Uninterruptible power supplies (UPS)
- DC drives
- AC motor controls

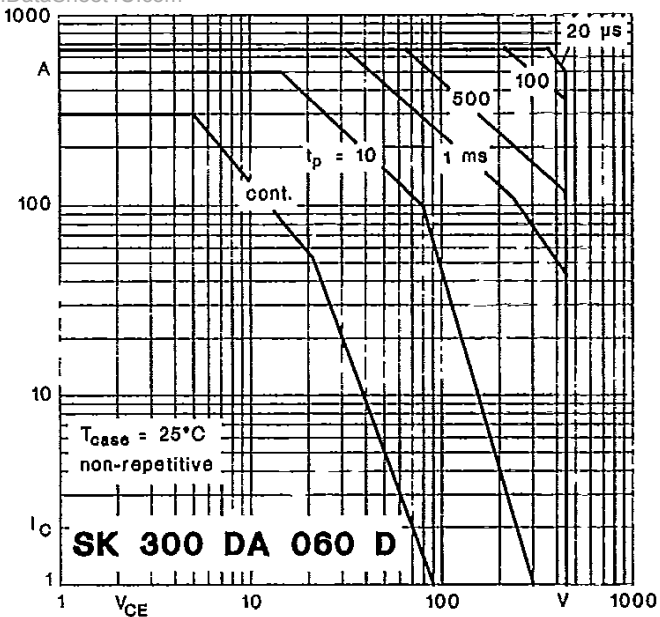


Fig. 1 Forward biased safe operating area (FBSOA)

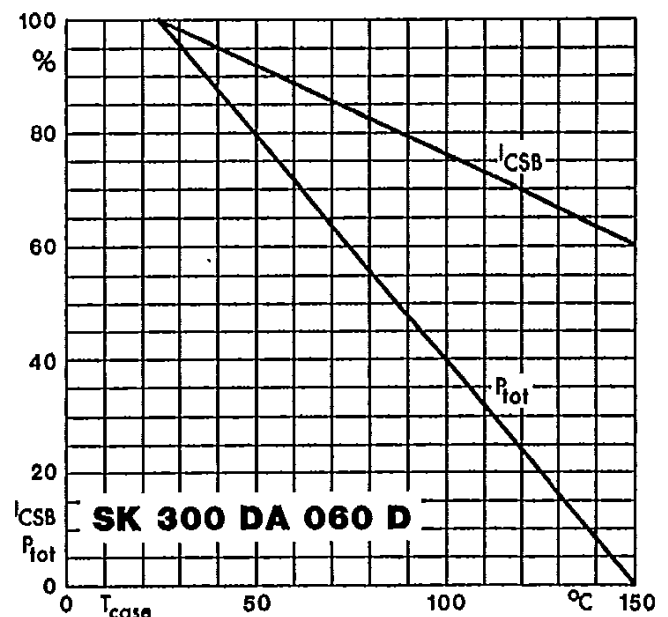


Fig. 2 Shifting the limits of the FBSOA with temperature

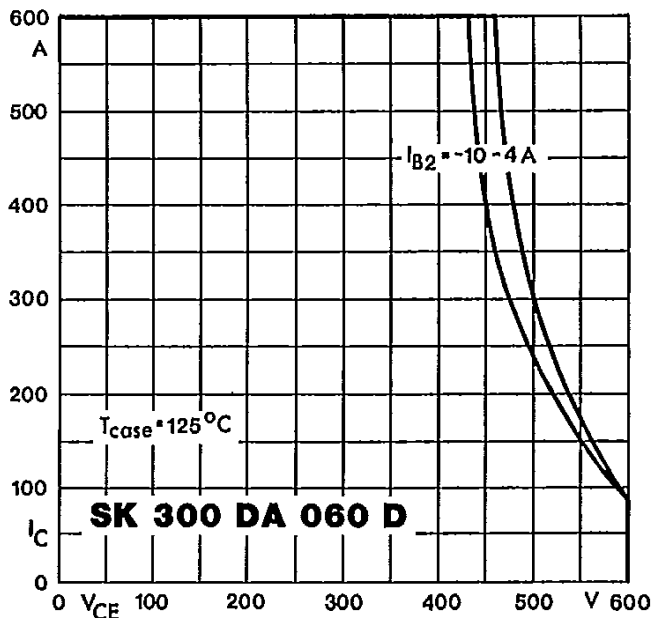


Fig. 3 Reverse biased safe operating area (RBSOA)

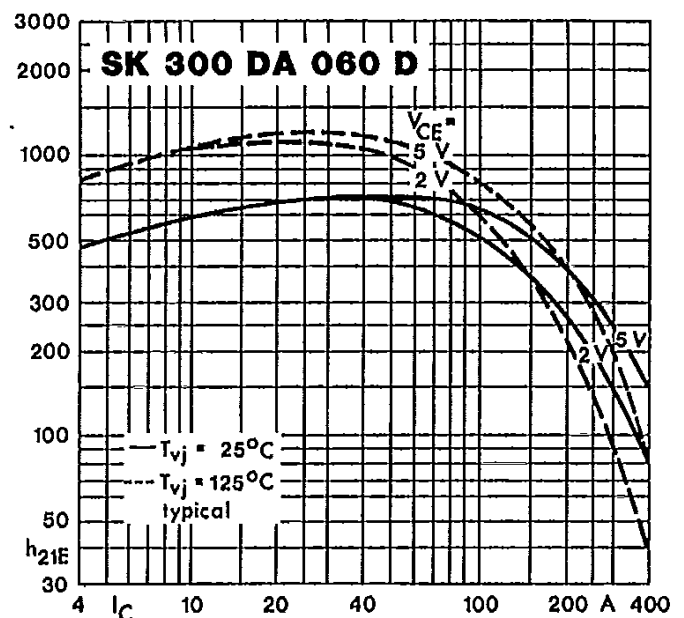


Fig. 4 Forward current transfer ratio vs. coll. current

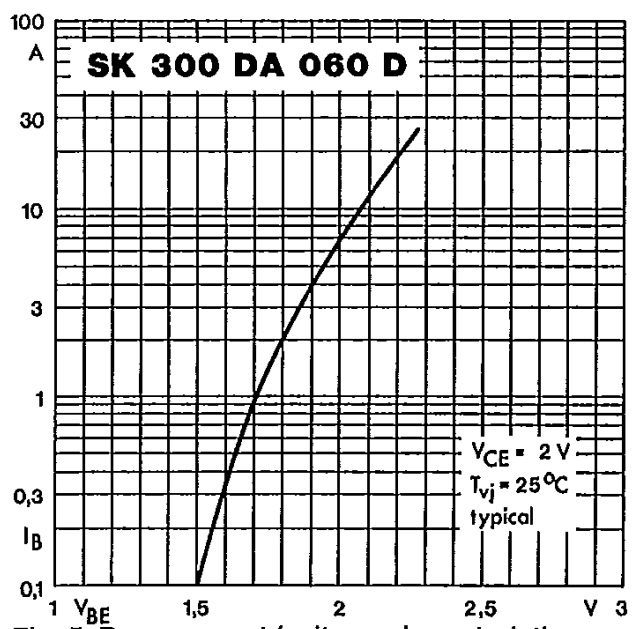


Fig. 5 Base current/voltage characteristic

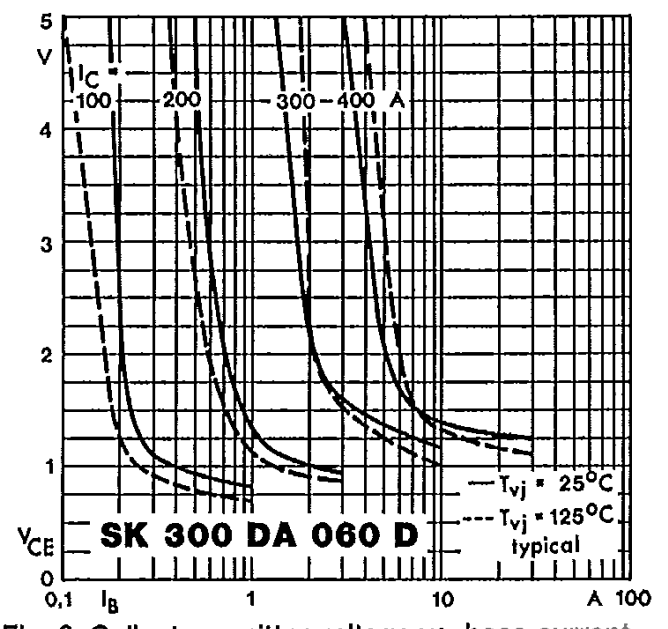


Fig. 6 Collector-emitter voltage vs. base current

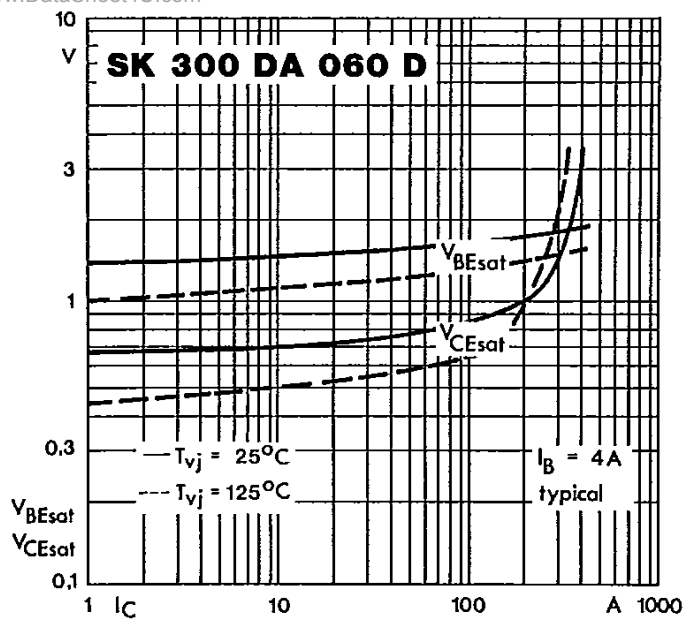


Fig. 7 Saturation voltages vs. collector current

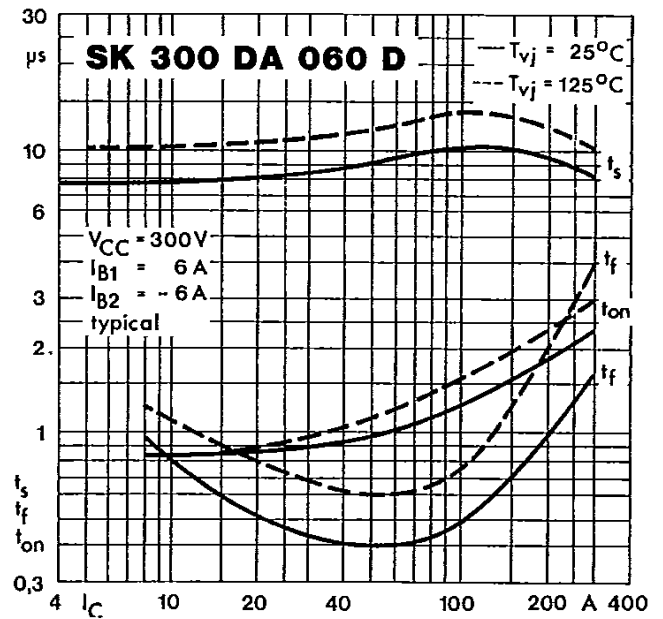


Fig. 8 Switching times vs. collector current

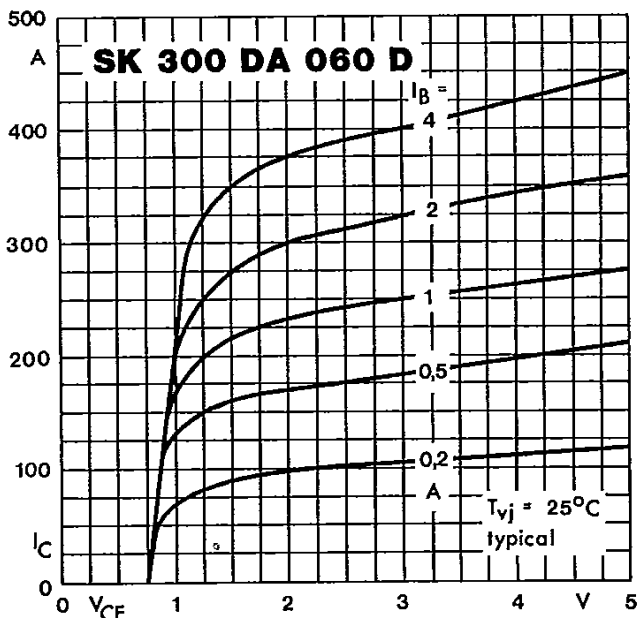


Fig. 9 Collector current/voltage characteristics

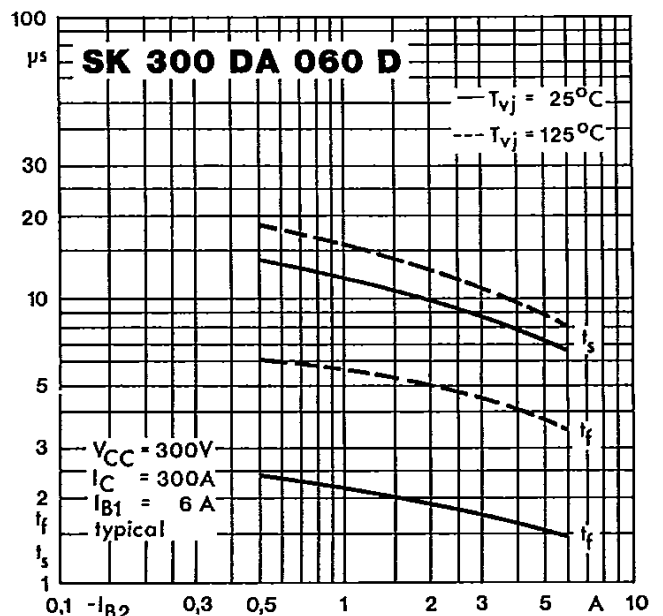


Fig. 10 Turn-off times vs. negative base current

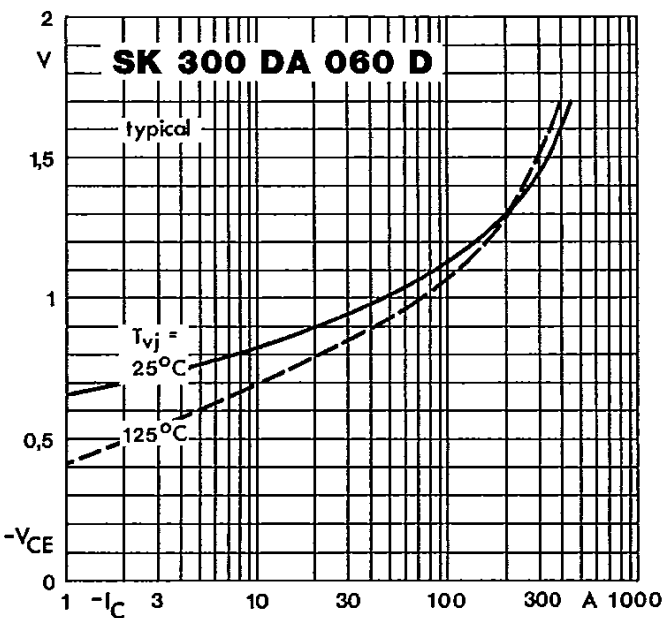


Fig. 11 Inverse diode forward characteristics

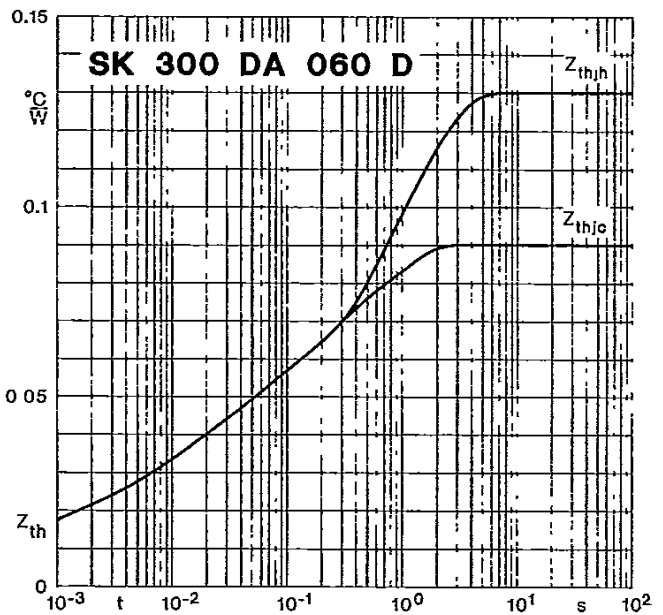


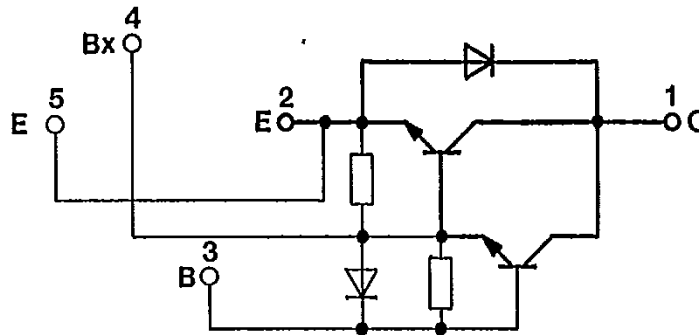
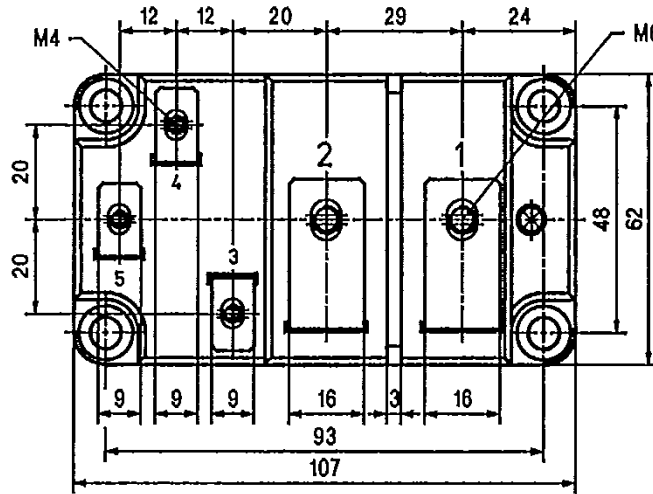
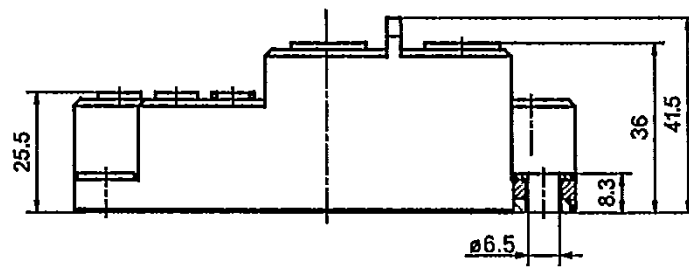
Fig. 12 Transient thermal impedance vs. time

# SK 300 DA 060 D

Case D 19

SEMITRANS® 4

UL recognized, file no. E 63 532



Dimensions in mm